S1MF

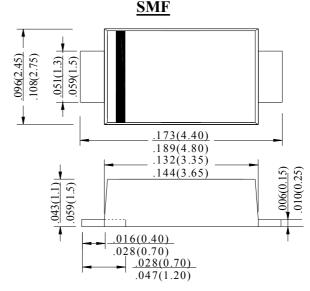
1.0AMP. GLASS PASSIVATED SURFACE MOUNT RECTIFIERS

FEATURE

- . High current capability
- . Low forward voltage drop
- . Low power loss, high efficiency
- . High temperature soldering guaranteed: $260^{\circ}\text{C}/10$ seconds at terminals.
- . For surface mounted application
- . Easy pick and place

MECHANICAL DATA

- . Case: Molded plastic
- . Epoxy: UL94V-0 rate flame retardant
- . Lead: MIL-STD- 202E, Method 208 guaranteed
- . Polarity: Color band denotes cathode end
- . Packaging:12mm tape per EIA STD RS-481
- . Mounting position: Any



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Single phase, half wave, 60Hz, resistive or inductive load.

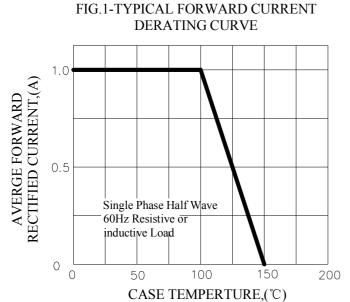
For capacitive load, derate current by 20%

Type Number	SYMBOL	S1MF	units
Maximum Recurrent Peak Reverse Voltage	$V_{ m RRM}$	1000	V
Maximum RMS Voltage	$V_{ m RMS}$	700	V
Maximum DC blocking Voltage	$V_{ m DC}$	1000	V
Maximum Average Forward Rectified Current at T_C =100°C	$I_{\mathrm{F(AV)}}$	1.0	A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	30.0	A
Maximum Forward Voltage at 1.0A DC	V_{F}	1.1	V
Maximum DC Reverse Current @T _C =25°C at rated DC blocking voltage @T _C =100°C	$I_{ m R}$	5.0 100.0	μА
Typical Junction Capacitance (Note1)	<i>C</i> j	12	pF
Typical Thermal Resistance (Note 2)	$R_{(JA)}$	90	°C /W
Typical Flictifial Resistance (Note 2)	$R_{(JC)}$	28	
Storage Temperature	$T_{\rm STG}$	-55 to +150	°C
Operation Junction Temperature	$T_{ m J}$	-55 to +150	°C

Note:

- 1. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
- 2. Measured on P.C.Board with 0.2×0.2"(5.0×5.0mm)Copper Pad Areas.

RATING AND CHARACTERISTIC CURVES (S1MF)



CHARACTERISTICS

10.0

(Y) 1.0

TJ=25°C

Pulse Width=300 \(\text{Ps} \)

1% Duty Cycle

1.0

1.0

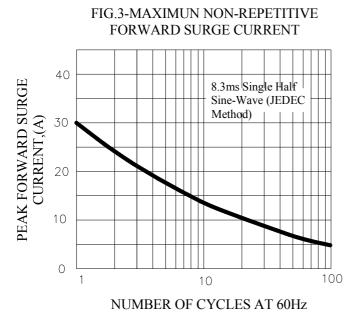
1.1

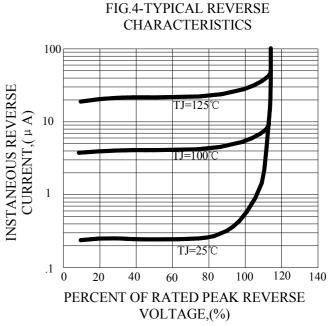
1.1

1.7

INSTANEOUS FORWARD VOLTAGE,(V)

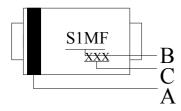
FIG.2-TYPICAL INSTANTANEOUS FORWARD





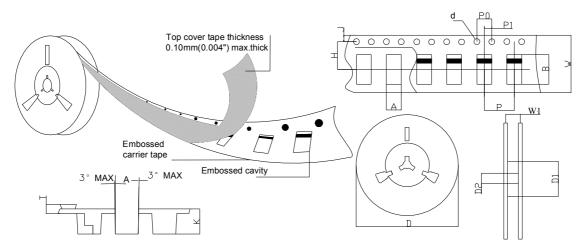
Marking and packaging illustration

1. Marking



SYMBOL	Explanation
A	Color Band Denotes Cathode
В	Product Name
С	Date Code

2. Packaging



SPECIFICATIONS mm(inch)	6	PACKAGE	
SYMBOL ITEM		SMF	
		ЭМГ	
Carrier width	A	2.93(0.115)Max	
Carrier length	В	4.85(0.191)Max	
Sprocket hole	d	ø1.55(0.061)Typ	
Reel outer diameter	D	330.0(13.0)Typ	
Reel inner diameter	D1	50.0(1.969)Min	
Feed hole diameter	D2	13.0(0.512)Typ	
Sprocket hole position	J	1.75(0.069)Typ	
Punch hole position	Н	5.50(0.217)Typ	
Carrier depth	K	1.42(0.056)Typ	
Punch hole pitch	P	4.00(0.157)Typ	
Sprocket hole pitch	P0	4.00(0.157)Typ	
Embossment center	P1	2.00(0.079)Typ	
Overall tape thickness	T	0.25(0.010)Typ	
Tape width	W	12.0(0.472)Typ	
Reel width	W1	12.4(0.488)Min	

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